Vishay General Semiconductor

Dual Common Cathode High Voltage Schottky Rectifier



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5.0 A			
V _{RRM}	90 V, 100 V			
I _{FSM}	120 A			
V _F	0.75 V			
T _J max.	150 °C			
Package	TO-220AB			
Diode variation	Dual common cathode			

FEATURES

- Trench MOS Schottky technology
- · Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

PARAMETER			MBR1090CT	MBR10100CT	UNIT
Max. repetitive peak reverse voltage			90	100	V
Working peak reverse voltage			90	100	V
Max. DC blocking voltage			90	100	V
Max. average forward rectified current at $T_C = 105 \ ^\circ C$	total device	I _{F(AV)}	10		А
	per diode		5.0		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			120		А
Non-repetitive avalanche energy at T_J = 25 °C, L = 60 mH per diode			60		mJ
Peak repetitive reverse current at t_p = 2 µs, 1 kHz, T_J = 38 °C ± 2 °C per diode			0.5		А
Voltage rate of change (rated V _R)			10 000		V/µs
Operating junction and storage temperature range		T _J , T _{STG}	-65 to +150		°C

(Pb) (e3) RoHS COMPLIANT





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MBR1090CT-E3, MBR10100CT-E3

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ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	MBR1090CT	MBR10100CT	UNIT	
Maximum instantaneous forward voltage per diode	I _F = 5.0 A	T _C = 125 °C	V _F ⁽¹⁾	0.75		V	
	$I_{F} = 5.0 \text{ A}$	T _C = 25 °C	VF \''	0.	85	v	
Maximum reverse current per diode at working peak		T _J = 25 °C	I _R ⁽²⁾	100		μA	
reverse voltage		T _J = 100 °C	'R \-/	6	.0	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	MBR1090CT	MBR10100CT	UNIT		
Typical thermal resistance per diode	$R_{\theta JC}$	4.4		°C/W		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR10100CT-E3/4W	1.87	4W	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

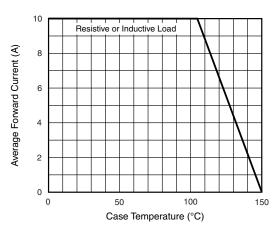


Fig. 1 - Forward Current Derating Curve

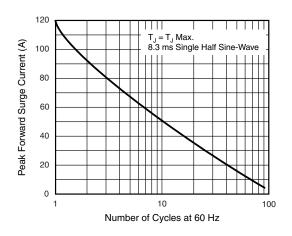


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

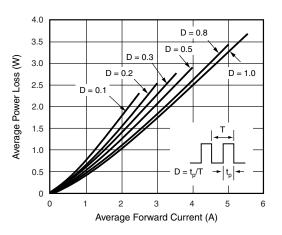


Fig. 3 - Forward Power Loss Characteristics Per Diode

Revision: 10-May-16

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Document Number: 89125

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MBR1090CT-E3, MBR10100CT-E3

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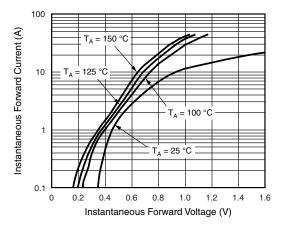


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

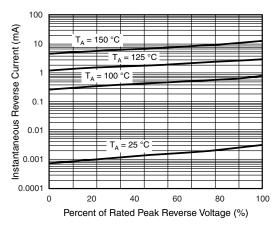


Fig. 5 - Typical Reverse Characteristics Per Diode

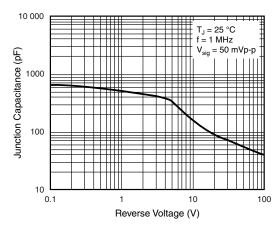


Fig. 6 - Typical Junction Capacitance Per Diode

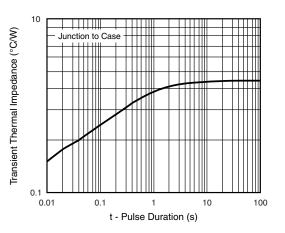


Fig. 7 - Typical Transient Thermal Impedance Per Diode

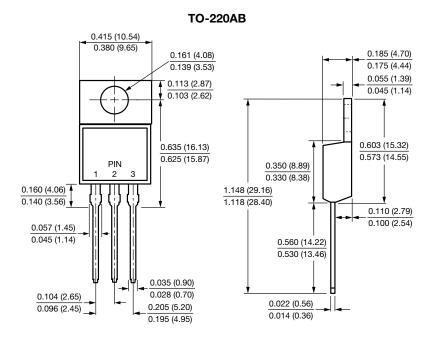
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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